

SPECIFICATION

• Supplier : Samsung electro-mechanics • Part Number : CL31C471JGFNNNE

• Product : Multi-layer Ceramic Capacitor • Description : CAP, 470pF, 500V, ±5%, C0G, 1206

A. Samsung Part Number

<u>CL</u> <u>31</u> <u>C</u> <u>471</u> <u>J</u> <u>G</u> <u>F</u> <u>N</u> <u>N</u> <u>N</u> <u>E</u> ① ② ③ ④ ⑤ ⑥ ⑦ ⑧ ⑨ ⑩ ⑪

1	Series	Samsung Multi-layer Ceramic Capacitor		
2	Size	1206 (inch code)	L: 3.2 ± 0.15 mm W: 1.6 ±	0.15 mm
3	Dielectric	C0G	8 Inner electrode Ni	
4	Capacitance	470 pF	Termination Cu	
(5)	Capacitance	±5 %	Plating Sn 100%	(Pb Free)
	tolerance			
6	Rated Voltage	500 V	® Special Reserved	d for future use
7	Thickness	1.25 ± 0.15 mm	① Packaging Embosse	ed Type, 7" reel

B. Samsung Reliablility Test and Judgement condition

	Performance	Test condition	
Capacitance	Within specified tolerance	1Mb±10% 0.5~5Vrms	
Q	1000 min		
Insulation	10,000Mohm or 500Mohm⋅μΓ	Rated Voltage 60~120 sec.	
Resistance	Whichever is Smaller		
Appearance	No abnormal exterior appearance	Microscope (×10)	
Withstanding	No dielectric breakdown or	150% of the rated voltage	
Voltage	mechanical breakdown		
Temperature	COG		
Characterisitcs	(From -55 ℃ to 125 ℃, Capacitance change shoud be within ±30PPM/℃)		
Adhesive Strength	No peeling shall be occur on the	500g·F, for 10±1 sec.	
of Termination	terminal electrode		
Bending Strength	Capacitance change :	Bending to the limit (1mm)	
	within ±5% or ±0.5pF whichever is larger	with 1.0mm/sec.	
Solderability	More than 75% of terminal surface	1) Sn63Pb37 solder	
	is to be soldered newly	235±5℃, 5±0.5sec.	
		2) SnAg3.0Cu0.5 solder	
		245±5℃, 3±0.3sec.	
		(preheating : 80~120℃ for 10~30sec.)	
Resistance to	Capacitance change :	Solder pot : 270±5℃, 10±1sec.	
Soldering heat	within ±2.5% or ±0.25pF whichever is larger		
	Tan δ, IR : initial spec.		

	Performance	Test condition
Vibration Test	Capacitance change :	Amplitude : 1.5mm
	within ±2.5% or ±0.25pF whichever is larger	From 10Hz to 55Hz (return : 1min.)
Tan δ, IR : initial spec.		2hours × 3 direction (x, y, z)
Humidity	Capacitance change :	40±2℃, 90~95%RH, 500+12/-0hrs
	within ±5% or ±0.5pF whichever is larger	
	Q: 350 min	
	IR: 1000Mohm or 50Mohm · μF	
	Whichever is Smaller	
Moisture	Capacitance change :	With rated voltage
Resistance within ±7.5% or ±0.75pF whichever is large		40±2℃, 90~95%RH, 500+12/-0hrs
	Q: 200 min	
	IR: 500Mohm or 25Mohm · μF	
	Whichever is Smaller	
High Temperature	Capacitance change :	With 120% of the rated voltage
Resistance	within ±3% or ±0.3pF whichever is larger	Max. operating temperature
	Q: 350 min	1000+48/-0hrs
	IR: 1000Mohm or 50Mohm · μF	
	Whichever is Smaller	
Temperature	Capacitance change :	1 cycle condition
Cycling	within ±2.5% or ±0.25pF whichever is larger	Min. operating temperatur → 25°C
	Tan δ, IR : initial spec.	→ Max. operating temperature → 25°C
		5 cycle test

C. Recommended Soldering method :

Reflow (Reflow Peak Temperature : 260+0/-5 $^{\circ}\!\text{C}$, 10sec. Max)

^{*} For the more detail Specification, Please refer to the Samsung MLCC catalogue.